74HC4520-Q100; 74HCT4520-Q100

Dual 4-bit synchronous binary counter

Rev. 3 — 9 October 2020

Product data sheet

1. General description

The 74HC4520-Q100; 74HCT4520-Q100 are dual 4-bit internally synchronous binary counters with two clock inputs (nCP0 and n $\overline{CP1}$). They have buffered outputs from all 4 bit positions (nQ0 to nQ3), and an asynchronous master reset input (nMR). The counter advances on either the LOW-to-HIGH transition of nCP0 when n $\overline{CP1}$ is HIGH. It also advances on the HIGH-to-LOW transition of n $\overline{CP1}$ if nCP0 is LOW. Either nCP0 or n $\overline{CP1}$ may be used as the clock input to the counter. The other clock input may be used as a clock enable input. A HIGH on nMR resets the counter (nQ0 to nQ3 = LOW) independent of nCP0 and n $\overline{CP1}$. Inputs include clamp diodes. It enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- · High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- · Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- Input levels:
 - For 74HC4520-Q100: CMOS level
 - For 74HCT4520-Q100: TTL level
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

3. Applications

- Multistage synchronous counting
- Multistage asynchronous counting
- Frequency dividers

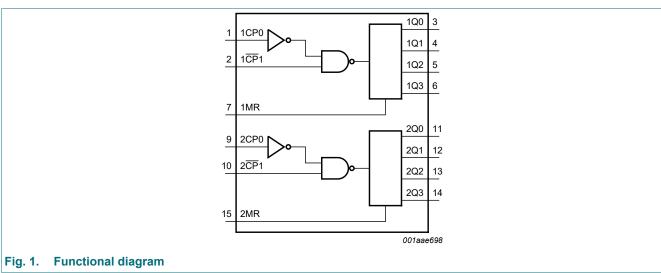


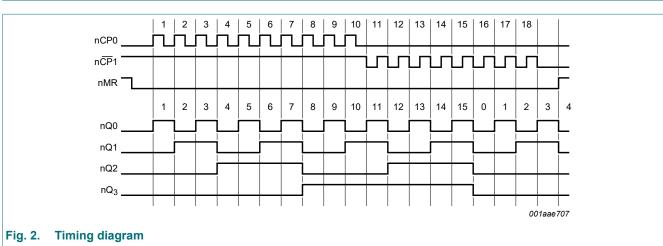
4. Ordering information

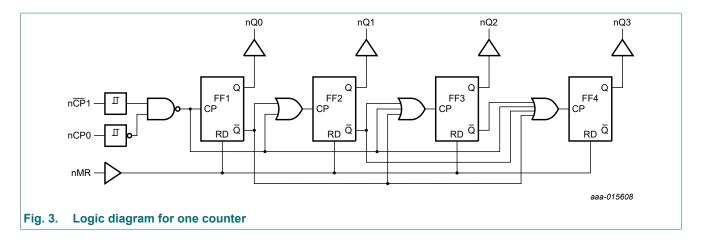
Table 1. Ordering information

Type number	Package	ckage									
	Temperature range	Name	Description	Version							
74HC4520D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1							
74HCT4520D-Q100			body width 3.9 mm								
74HC4520PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1							

5. Functional diagram

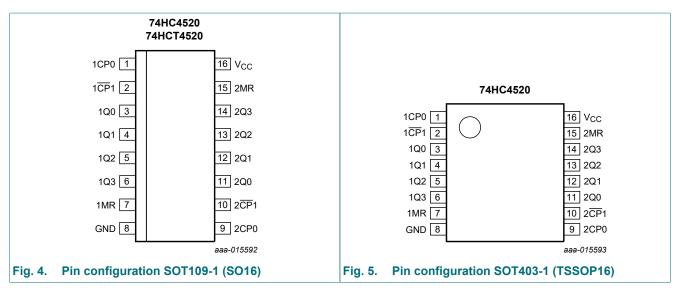






6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1CP0, 2CP0	1, 9	clock input (LOW-to-HIGH edge-triggered)
1CP1, 2CP1	2, 10	clock input (HIGH-to-LOW edge-triggered)
1Q0 to 1Q3	3, 4, 5, 6	output
1MR, 2MR	7, 15	asynchronous master reset input (active HIGH)
GND	8	ground (0 V)
2Q0 to 2Q3	11, 12, 13, 14	output
V _{CC}	16	supply voltage

7. Functional description

Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care; \ \uparrow = positive-going \ transition; \ \downarrow = negative-going \ transition.$

nCP0	nCP1	nMR	Mode
↑	Н	L	counter advances
L	\downarrow	L	counter advances
↓	X	L	no change
X	\uparrow	L	no change
↑	L	L	no change
Н	\downarrow	L	no change
X	Х	Н	nQ0 to nQ3 = LOW

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	[1]	-	500	mW

^[1] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC4520-Q100			74H	Unit		
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC45	20-Q100									
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80.0	-	160.0	μA
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT4	520-Q100	1			ı			I		
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								<u> </u>
	output voltage	Ι _O = 20 μΑ	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max		
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ	
I _{CC}	supply current	rent $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$		-	8.0	-	80.0	-	160.0	μΑ	
supply current o		per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V ; $I_O = 0 \text{ A}$									
		pin nCP0, nCP1	-	80	288	-	360	-	392	μΑ	
		pin nMR	-	150	540	-	675	-	735	μΑ	
Cı	input capacitance		-	3.5	-	-	-	-	-	pF	

11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit, see Fig. 8.

Symbol	Parameter	er Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC45	20-Q100					•		•		
t _{pd}	propagation	nCP0 to nQn; see Fig. 6 [1]								
	delay	V _{CC} = 2.0 V	-	77	240	-	300	-	360	ns
		V _{CC} = 4.5 V	-	28	48	-	60	-	72	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	24	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	22	41	-	51	-	61	ns
		nCP1 to nQn; see Fig. 6 [1]								
		V _{CC} = 2.0 V	-	77	240	-	300	-	360	ns
		V _{CC} = 4.5 V	-	28	48	-	60	-	72	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	24	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	22	41	-	51	-	61	ns
t _{PHL}		nMR to nQn; see Fig. 6								
	propagation delay	V _{CC} = 2.0 V	-	44	150	-	190	-	225	ns
	delay	V _{CC} = 4.5 V	-	16	30	-	38	-	45	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	13	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	13	26	-	33	-	38	ns
t _t	transition	nQn; see Fig. 6 [2]								
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns

Symbol	Parameter	Conditions		25 °C			C to		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _W	pulse width	nCP0, nCP1 HIGH or LOW; see Fig. 7								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
		nMR HIGH; see Fig. 7								
		V _{CC} = 2.0 V	120	39	-	150	-	180	-	ns
		V _{CC} = 4.5 V	24	14	-	30	-	36	-	ns
		V _{CC} = 6.0 V	20	11	-	26	-	31	-	ns
t _{rec}	recovery time	nMR to nCP0, nCP1; see Fig. 7								
		V _{CC} = 2.0 V	0	-28	-	0	-	0	-	ns
		V _{CC} = 4.5 V	0	-10	-	0	-	0	-	ns
		V _{CC} = 6.0 V	0	-8	-	0	-	0	-	ns
t _{su}	set-up time	nCP0 to nCP1; nCP1 to nCP0; see Fig. 6								
		V _{CC} = 2.0 V	80	14	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	4	-	17	-	20	-	ns
f _{max}	maximum	nCP0, nCP1; see Fig. 7								
	frequency	V _{CC} = 2.0 V	6	19	-	4.8	-	4	-	MHz
		V _{CC} = 4.5 V	30	58	-	24	-	20	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	68	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	69	-	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}; V_{CC} = 5 \text{ V};$ [3] $f_i = 1 \text{ MHz}$	-	29	-	-	-	-	-	pF
74HCT4	520-Q100									
t _{pd}	propagation	nCP0 to nQn; see Fig. 6 [1]								T
	delay	V _{CC} = 4.5 V	-	28	53	-	66	-	80	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	24	-	-	-	-	-	ns
		nCP1 to nQn; see Fig. 6 [1]								1
		V _{CC} = 4.5 V	-	25	53	-	66	-	80	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	24	-	-	-	-	-	ns
t _{PHL}	HIGH to LOW	nMR to nQn; see Fig. 6								
	propagation	V _{CC} = 4.5 V	-	16	35	-	44	-	53	ns
	delay	V _{CC} = 5.0 V; C _L = 15 pF	-	13	-	-	-	-	-	ns
t _t	transition	nQn; see Fig. 6 [2]								
	time	V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
t _W	pulse width	nCP0, nCP1 HIGH or LOW; see Fig. 7								
		V _{CC} = 4.5 V	20	10	-	25	-	30	-	ns
		nMR HIGH; see Fig. 7								
		V _{CC} = 4.5 V	20	12	-	25	-	30	-	ns

Symbol Parameter		Conditions		25 °C			-40 °C to +85 °C		-40 °C to +125 °C	
			Min	Тур	Max	Min	Max	Min	Max	
t _{rec} recovery time		nMR to nCP0, nCP1; see Fig. 7								
		V _{CC} = 4.5 V	0	-8	-	0	-	0	-	ns
		nCP0 to nCP1; nCP1 to nCP0; see Fig. 6								
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
f _{max}	maximum	nCP0, nCP1; see Fig. 7								
	frequency	V _{CC} = 4.5 V	30	58	-	24	-	20	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	64	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC} - 1.5 \text{ V}; V_{CC} = 5 \text{ V}; [3]$ $f_i = 1 \text{ MHz}$	-	24	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} . [2] t_t is the same as t_{THL} and t_{TLH} . [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W): $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

f_i = input frequency in MHz;

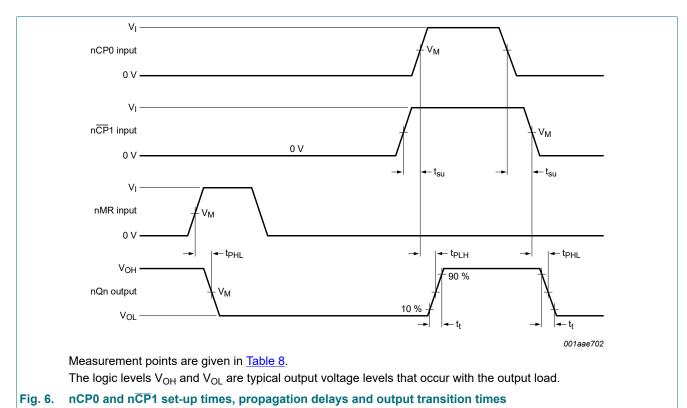
 f_o = output frequency in MHz;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

11.1. Waveforms and test circuit



1/f_{max}

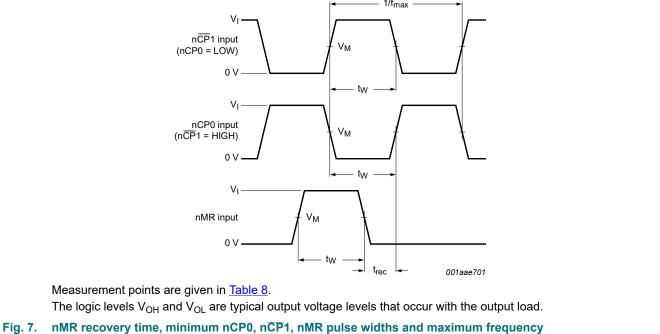
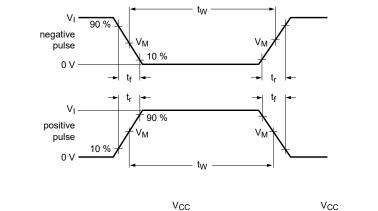
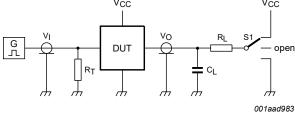


Table 8. Measurement points

rabic of incasarcinicit points			
Туре	Input	Output	
	V _M	V _I	V _M
74HC4520-Q100	0.5 × V _{CC}	GND to V _{CC}	0.5 × V _{CC}
74HCT4520-Q100	1.3 V	GND to 3 V	1.3 V





Test data is given in Table 9.

Test circuit definitions:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator

C_L = Load capacitance including jig and probe capacitance

R_L = Load resistance.

S1 = Test selection switch

Fig. 8. Test circuit for measuring switching times

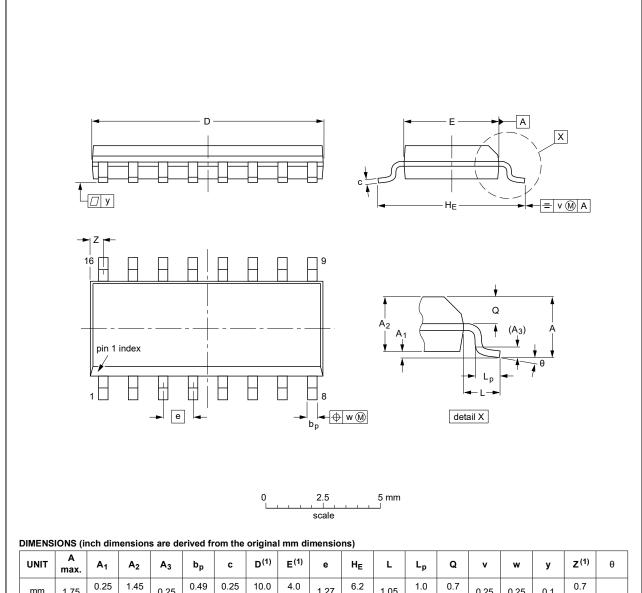
Table 9. Test data

Туре	Input		Load	S1 position	
	V _I	t _r , t _f C _L		R_L	t _{PHL} , t _{PLH}
74HC4520-Q100	GND to V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT4520-Q100	GND to 3 V	6 ns	15 pF, 50 pF	1 kΩ	open

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

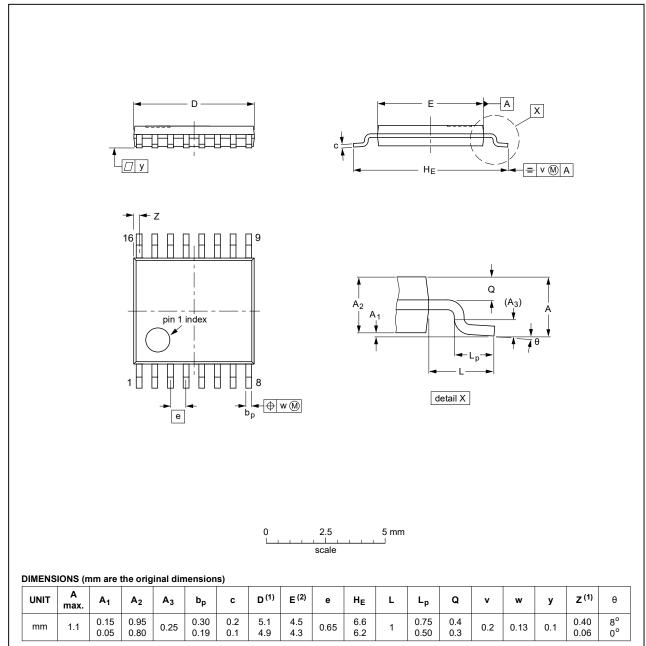
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig. 9. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				99-12-27 03-02-18	

Fig. 10. Package outline SOT403-1 (TSSOP16)

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT4520_Q100 v.3	20201009	Product data sheet	-	74HC_HCT4520_Q100 v.2			
Modifications:	 Type number 74HC4520PW-Q100 (SOT403-1/TSSOP16) added. Section 2 updated. Table 4: Derating values for P_{tot} total power dissipation have been updated. 						
74HC_HCT4520_Q100 v.2	20190214	Product data sheet	-	74HC_HCT4520_Q100 v.1			
Modifications:	guidelines o Legal texts h	of this data sheet has been f Nexperia. nave been adapted to the r r 74HC4520PW-Q100 (SC	new company nan	ne where appropriate.			
74HC_HCT4520_Q100 v.1	20141204	Product data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This Nexperia product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or

equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Contents

1. General description	<i>'</i>
2. Features and benefits	
3. Applications	<i>'</i>
4. Ordering information	2
5. Functional diagram	2
6. Pinning information	3
6.1. Pinning	3
6.2. Pin description	3
7. Functional description	4
8. Limiting values	4
9. Recommended operating conditions	4
10. Static characteristics	!
11. Dynamic characteristics	6
11.1. Waveforms and test circuit	9
12. Package outline	1′
13. Abbreviations	13
14. Revision history	1
15. Legal information	14

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 9 October 2020

[©] Nexperia B.V. 2020. All rights reserved